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COMMUNICATION

Decay of Charge Deposited on the
Wall of a Gaseous Void

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ABSTRACT

Following partial discharge activity within a gaseous void, charges will accumulate on the wall of the void. In the present paper, the decay of such charges due to surface currents at the void wall is studied analytically, and the factors affecting this decay are indicated.

INTRODUCTION

PARTIAL discharges can occur in a gaseous void within solid insulation. Such discharges deposit free charges on the void wall. Depending on the polarity of the applied field, the electric field produced by these wall charges can either inhibit or promote further discharge development. However, should the void wall exhibit a finite surface conductivity, the wall charges will become neutralized in time by surface currents at the wall. This behavior will lead to a time-dependent wall charge field. In the present paper, the decay of the surface charge is investigated theoretically, and the factors influencing this decay are discussed.

CONTINUITY EQUATION FOR
SURFACE CURRENTS

THE surface in question is considered to be the interface between a medium 'a' and a medium 'b'. The latter is a sphere of radius R , while the former occupies the remaining space which extends to infinity. Hence with respect to spherical coordinates r, θ, ψ the interface is represented by the surface $r = R$. As we are examining the behavior of surface currents due to an interface which

exhibits a finite surface conductivity Γ , the relevant continuity equation is

$$\vec{\nabla}_s \cdot \vec{K} + \frac{\partial \sigma}{\partial t} = 0 \quad (1)$$

where \vec{K} is the surface current density, σ the surface charge density and t time. $\vec{\nabla}_s \cdot \vec{K}$ represents the surface divergence of \vec{K} [1]. \vec{K} is related to the tangential electric field strength \vec{E}_t at the surface by

$$\vec{K} = \Gamma \vec{E}_t \quad (2)$$

Employing the continuity equation in the above form implies that, in this study, the volume conduction current density \vec{J} is zero in each medium. Before proceeding with the present analysis, it will be assumed that the surface conductivity is homogeneous and isotropic such that a linear relationship exists between \vec{K} and \vec{E}_t .

For the present class of boundary value problems, the general potential functions associated with the two media bounding the interface can be expressed as [2]

$$\Phi_a(r, \theta, \psi, t) = \varphi_a(r, \theta, \psi)T(t) \quad (3)$$

$$\Phi_b(r, \theta, \psi, t) = \varphi_b(r, \theta, \psi)T(t) \quad (4)$$

where φ_a and φ_b represent the time zero potential distributions in medium 'a' and medium 'b', respectively, and

are thus solutions of Laplace's equation. The temporal variation T is a function of t alone with $T(0) = 1$.

By considering the field boundary conditions associated with \vec{K} and σ , it is possible to derive the equivalent continuity equation to be fulfilled by the potential functions Φ_a and Φ_b at the spherical interface [2]. For $r = R$, one obtains

$$\frac{\Gamma}{r^2} \frac{\partial}{\partial r} \left[r^2 \frac{\partial \varphi}{\partial r} \right] T + \left[\epsilon_b \frac{\partial \varphi_b}{\partial r} - \epsilon_a \frac{\partial \varphi_a}{\partial r} \right] \frac{dT}{dt} = 0 \quad (5)$$

In (5) the form of the first term, which is related to $\vec{\nabla}_s \cdot \vec{K}$, arises because the potential distributions in the two media bounding the interface are solutions of Laplace's equation. Hence as this term is concerned with the second derivative of the potential, the term can be derived from either φ_a or φ_b , i.e. the lack of a potential subscript in this term is not a misprint. In deriving (5), the orientation of the interface is such that $r_a \geq r_b$. In addition, it must be emphasized that the derivation of (5) is based on the assumption of a constant Γ .

As the bracketed terms in (5) are independent of t , the solution to this differential equation is

$$T = \exp(-\lambda t) \quad (6)$$

with

$$\lambda = \frac{\frac{\Gamma}{r^2} \frac{\partial}{\partial r} \left[r^2 \frac{\partial \varphi}{\partial r} \right]}{\left[\epsilon_b \frac{\partial \varphi_b}{\partial r} - \epsilon_a \frac{\partial \varphi_a}{\partial r} \right]} \quad (7)$$

Consequently the general potential solutions are

$$\Phi_a = \varphi_a \exp(-\lambda t) \quad (8)$$

$$\Phi_b = \varphi_b \exp(-\lambda t) \quad (9)$$

φ_a and φ_b are deduced from the interfacial charge distribution at time $t = 0$.

APPLICATION TO A SPHERICAL VOID

As the initial discharge development in the void is presumed to be axially symmetric, we consider the wall charge distribution to exhibit the same symmetry. In such situations, the appropriate solutions for the time zero potentials are

$$\varphi_a = \sum_{n=0}^{\infty} A_n \left[\frac{R}{r} \right]^{n+1} P_n(\cos \theta) \quad \text{for } r \geq R \quad (10)$$

$$\varphi_b = \sum_{n=0}^{\infty} A_n \left[\frac{r}{R} \right]^n P_n(\cos \theta) \quad \text{for } r \leq R \quad (11)$$

where $P_n(\cos \theta)$ is a Legendre polynomial. At the void wall ($r = R$), φ_a and φ_b automatically fulfill the potential-equality requirement. As the solutions for φ_a and φ_b in

terms of spherical coordinates consist of infinite series, (7) cannot be used directly to determine the relevant λ . In this situation reference must be made to (5) from which, upon differentiating (10) and (11), we find that, for $r = R$,

$$\lambda_n = \frac{n(n+1)}{(n+1)\epsilon_{ra} + n\epsilon_{rb}} \left[\frac{1}{\tau} \right] \quad (12)$$

with $\tau = \epsilon_o R / \Gamma$. In (12), ϵ_r is used to denote relative permittivity. The potential solutions associated with the two media are thus

$$\Phi_a = \sum_{n=0}^{\infty} A_n \left[\frac{R}{r} \right]^{n+1} P_n(\cos \theta) \exp \left[\frac{-n(n+1)}{(n+1)\epsilon_{ra} + n\epsilon_{rb}} \frac{t}{\tau} \right] \quad (13)$$

$$\Phi_b = \sum_{n=0}^{\infty} A_n \left[\frac{r}{R} \right]^n P_n(\cos \theta) \exp \left[\frac{-n(n+1)}{(n+1)\epsilon_{ra} + n\epsilon_{rb}} \frac{t}{\tau} \right] \quad (14)$$

To determine A_n it is necessary to consider the nature of the initial charge distribution.

As a first approach, let q be a point charge located on the void wall coincident with the axis of symmetry ($r = R$, $\theta = 0$). From the potential solution for a dielectric sphere and a point charge given in standard textbooks [3,4], we can deduce that

$$A_n = \frac{q}{4\pi\epsilon_o R} \left[\frac{2n+1}{(n+1)\epsilon_{ra} + n\epsilon_{rb}} \right] \quad (15)$$

and thus the associated potential solutions are

$$\Phi_a = \frac{q}{4\pi\epsilon_o R} \sum_{n=0}^{\infty} \left\{ \frac{2n+1}{(n+1)\epsilon_{ra} + n\epsilon_{rb}} \left[\frac{R}{r} \right]^{n+1} \times P_n(\cos \theta) \exp \left[\frac{-n(n+1)}{(n+1)\epsilon_{ra} + n\epsilon_{rb}} \frac{t}{\tau} \right] \right\} \quad (16)$$

$$\Phi_b = \frac{q}{4\pi\epsilon_o R} \sum_{n=0}^{\infty} \left\{ \frac{2n+1}{(n+1)\epsilon_{ra} + n\epsilon_{rb}} \left[\frac{r}{R} \right]^n \times P_n(\cos \theta) \exp \left[\frac{-n(n+1)}{(n+1)\epsilon_{ra} + n\epsilon_{rb}} \frac{t}{\tau} \right] \right\} \quad (17)$$

For $\epsilon_{ra} = 1$ and $\epsilon_{rb} > 1$, (16) and (17) represent the potential solutions for a charged, insulating spherical particle. As $t \rightarrow \infty$, the charge will become dispersed around the spherical surface to form a shell of uniform charge density. Confirmation of this behavior is obtained on expanding the series in (16) and (17) and taking the limit for $t \rightarrow \infty$.

A void is however a closed volume, and thus the net charge within any void following partial discharge activity will remain zero. Consequently to represent this condition, it is necessary to consider a second wall charge, of

opposite polarity, located diametrically opposite the first charge, i.e. $-q$ at $r = R$, $\theta = \pi$. Using the principle of superposition, we can obtain the composite solutions for Φ_a and Φ_b by simply adding appropriate solutions of the types given in (16) and (17). For $-q$, $P_n(\cos \theta)$ is replaced by $P_n(\cos[\pi - \theta])$. Because we have

$$P_n(\cos \theta) - P_n(-\cos \theta) = 0 \quad (18)$$

for n even, while for n odd

$$P_n(\cos \theta) - P_n(-\cos \theta) = 2P_n(\cos \theta) \quad (19)$$

we can express the composite potentials in a more convenient form on replacing n by $2n+1$. This substitution leads to

$$\Phi_{a0} = \frac{q}{2\pi\epsilon_o R} \sum_{n=0}^{\infty} \left\{ \frac{4n+3}{(2n+2)\epsilon_{ra} + (2n+1)\epsilon_{rb}} \times \left[\frac{R}{r} \right]^{2n+2} P_{2n+1}(\cos \theta) \times \exp \left[\frac{-(2n+1)(2n+2)}{(2n+2)\epsilon_{ra} + (2n+1)\epsilon_{rb}} \frac{t}{\tau} \right] \right\} \quad (20)$$

$$\Phi_{b0} = \frac{q}{2\pi\epsilon_o R} \sum_{n=0}^{\infty} \left\{ \frac{4n+3}{(2n+2)\epsilon_{ra} + (2n+1)\epsilon_{rb}} \times \left[\frac{r}{R} \right]^{2n+1} P_{2n+1}(\cos \theta) \times \exp \left[\frac{-(2n+1)(2n+2)}{(2n+2)\epsilon_{ra} + (2n+1)\epsilon_{rb}} \frac{t}{\tau} \right] \right\} \quad (21)$$

The subscript 0 indicates that these potential functions relate to a zero net charge condition in the void and hence, as $t \rightarrow \infty$, the values of both Φ_{a0} and Φ_{b0} should tend to zero. This condition is fulfilled, because $n = 0$ in (20) and (21) does not produce a time-independent term. With $\epsilon_{rb} = 1$, the above expressions will represent the potential variations in the bulk material (Φ_{a0}) and in the void (Φ_{b0}) when a simple point-charge configuration is used to simulate the void wall charges at time zero.

SURFACE CHARGE DENSITY AT VOID WALL

FOR the situation under discussion, the surface charge density σ at the void wall is given by

$$\sigma = \epsilon_b \frac{\partial \Phi_b}{\partial r} - \epsilon_a \frac{\partial \Phi_a}{\partial r} \quad \text{for } r = R \quad (22)$$

Hence upon differentiating (20) and (21) and inserting in (22), we obtain for $\epsilon_{rb} = 1$

$$\sigma = 2\sigma_o \sum_{n=0}^{\infty} \left\{ (4n+3) P_{2n+1}(\cos \theta) \times \exp \left[\frac{-(2n+1)(2n+2)}{(2n+2)\epsilon_{ra} + (2n+1)} \frac{t}{\tau} \right] \right\} \quad (23)$$

where

$$\sigma_o = \frac{q}{4\pi R^2} \quad (24)$$

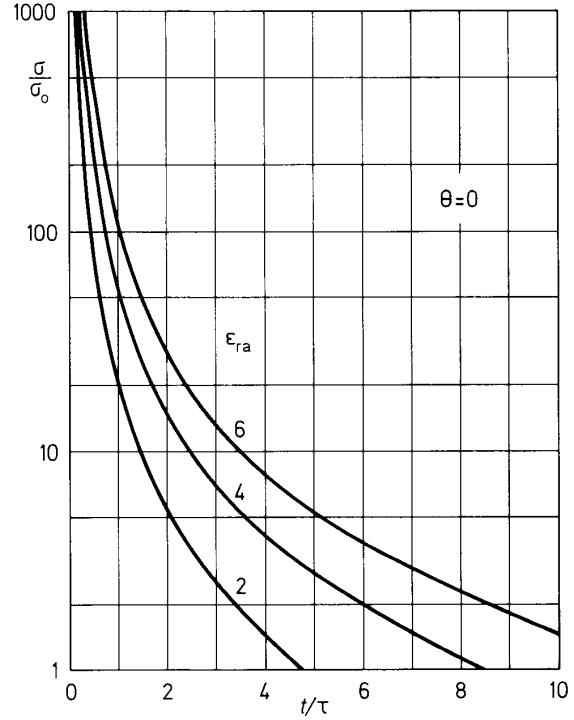


Figure 1.

Temporal variation of the surface charge density σ at the time-zero charge location.

The temporal variation of σ at the time-zero location of the charge is illustrated in Figure 1. σ decays monotonically with t , but as the value of σ is obtained from the summation of many exponential terms, see (23), the decay is not truly exponential in nature. Moreover, the greater the value of the bulk permittivity, the slower will be the observed rate of this decay.

At locations which are charge-free at $t = 0$, σ increases initially to some maximum value and thereafter decays, see Figure 2. The value of the bulk permittivity influences both the time to the maximum σ -value (t_{max}) and the value itself (σ_{max}). The variation in σ_{max} is relatively minor. However, both σ_{max} and t_{max} are strongly influenced by the proximity of the surface location in question to that of the time-zero source position.

The variation of σ around the void wall is shown in Figures 3 and 4. The former indicates the influence of ϵ_{ra} for t constant, whereas the latter shows the evolution

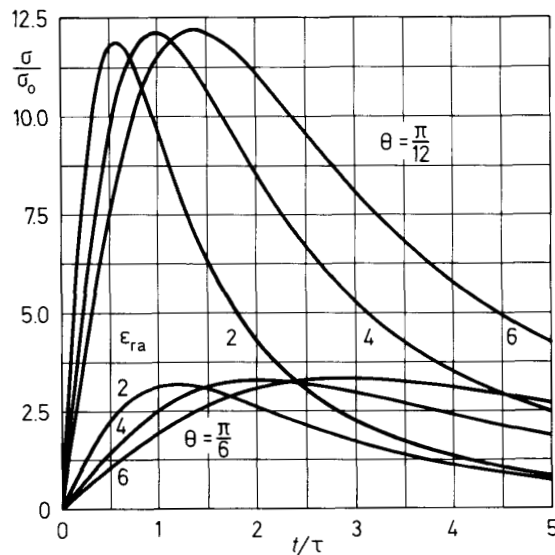


Figure 2.

Temporal variation of the surface charge density σ at locations which are charge-free at time zero.

of σ for $\epsilon_{ra} = 4$. It is evident from Figures 3 and 4 that wall charge takes a considerable number of time constants ($> 5\tau$) to disperse, and that the absolute time is strongly influenced by the bulk permittivity.

AXIAL ELECTRIC FIELD ACROSS THE VOID

THE repetition rate of void discharges is controlled by the time taken to re-establish a void field of sufficient magnitude to support discharge growth. Among other parameters, this time will be influenced by the decay of the field produced by wall charges. As a means of portraying this field, the variation of the field strength E_{ax} along the void axis is considered. With reference to E_{ax} we have $(\partial\Phi_b/\partial\theta) = 0$ and thus the axial field strength is given simply by

$$E_{ax} = -\frac{\partial\Phi_b}{\partial r} \quad (25)$$

Hence upon differentiating (21) we obtain, for $\epsilon_{rb} = 1$,

$$E_{ax} = -2E_o \sum_{n=0}^{\infty} \left\{ \frac{(4n+3)(2n+1)}{(2n+2)\epsilon_{ra} + (2n+1)} \left[\frac{r}{R} \right]^{2n} \times \right. \\ \left. P_{2n+1}(\cos\theta) \exp \left[\frac{-(2n+1)(2n+2)}{(2n+2)\epsilon_{ra} + (2n+1)} \frac{t}{\tau} \right] \right\} \quad (26)$$

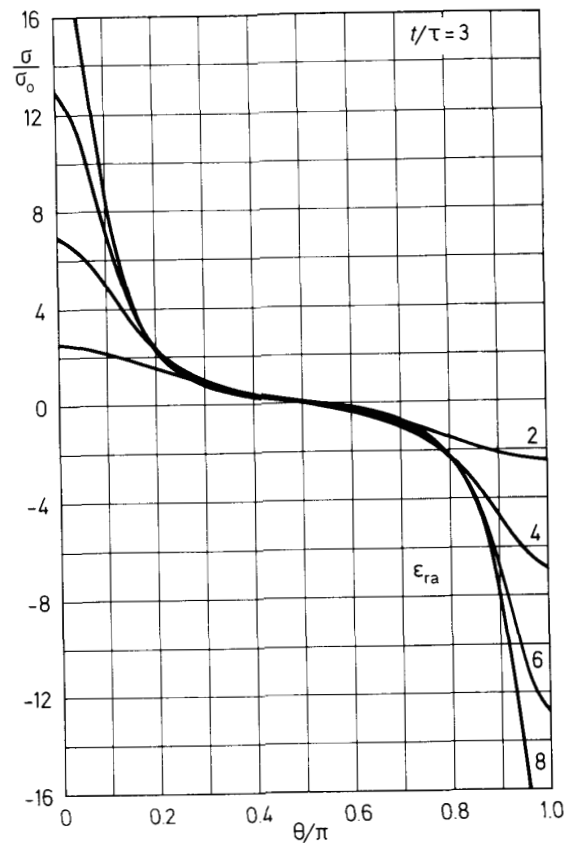


Figure 3.

Spatial variation of surface charge density σ at void wall: influence of bulk permittivity.

where

$$E_o = \frac{q}{4\pi\epsilon_o R^2} \quad (27)$$

It should be remembered that along the void axis $\theta = 0$ or $\theta = \pi$, and hence $P_{2n+1}(\cos\theta) = \pm 1$ for $0 \leq r/R \leq 1$

To illustrate the influence of the bulk polarization upon the \vec{E} field in the void, the variation of E_{ax} at time zero is shown in Figure 5 for different bulk permittivities. $\epsilon_{ra} = 1$ corresponds to the field between two point charges. From this diagram it is clear that the larger ϵ_{ra} is the smaller is the field in the void.

The bulk permittivity has also an influence upon the rate at which the axial field decays. This aspect is indicated in Figure 6, which illustrates the variation of E_{ax} for different values of ϵ_{ra} at $t/\tau = 3$. These field distributions are generated from the σ distributions shown in Figure 3, from which the influence of ϵ_{ra} upon E_{ax} can be readily appreciated.

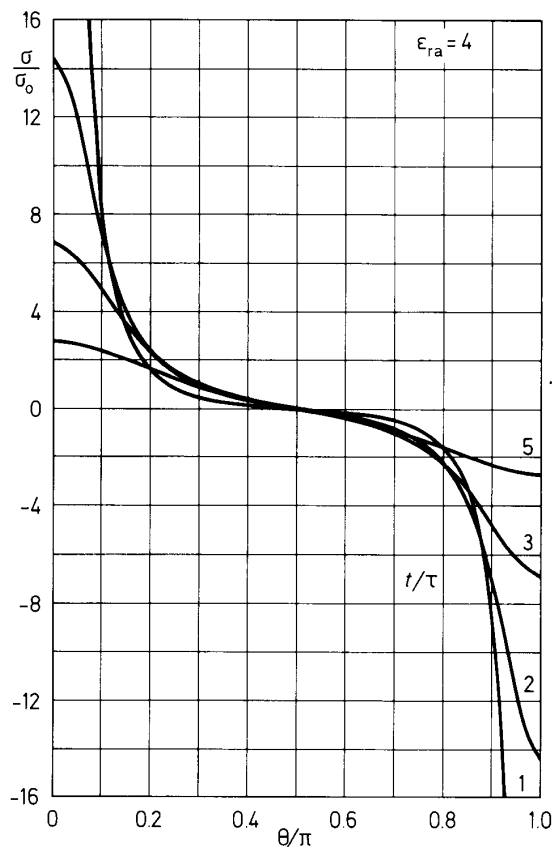


Figure 4.

Spatial variation of surface charge density σ at void wall: influence of time.

The temporal development of E_{ax} for $\epsilon_{ra} = 4$ is displayed in Figure 7. The graphs indicate that as time increases, the void field decreases in magnitude and its degree of nonuniformity is steadily reduced. The corresponding σ distributions are given in Figure 4.

DISCUSSION AND CONCLUSION

ON the basis of the temporal potential distribution associated with a charged dielectric particle (cf. gas/solid), it has been possible to derive the corresponding distribution for a wall charged void. This void potential distribution is derived by not only interchanging the media permittivities (cf. solid/gas), but also by taking account of the inherent zero net charge condition in a void. This zero net charge condition is fulfilled by superimposing a second particle type solution for a source

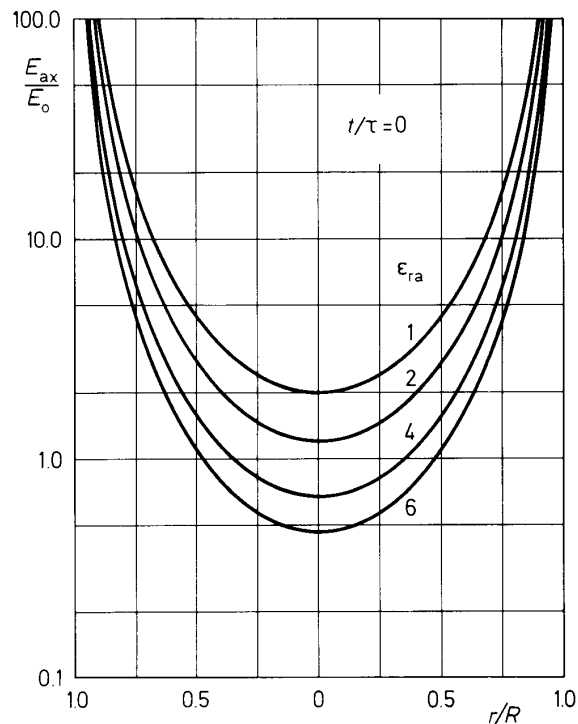


Figure 5.

Variation of the void axial electric field E_{ax} at time zero: influence of bulk permittivity.

charge of opposite polarity. Although partial discharges in a gaseous void create charges, it should be remembered that, as the void is a closed volume, the net charge in the void remains zero.

The examination of the wall charge decay indicates that, in terms of the basic time constant $\epsilon_0 R/\Gamma$, this process can take a considerable time. The decay rate is significantly reduced by an increase in the permittivity of the bulk medium. The dominating influence of this permittivity is likewise reflected in the increased duration and thereby prolonged inhomogeneity of the electric field sustained in the void. However the absolute value of this field is reduced with an increase in bulk permittivity.

In conclusion, the present choice of a point charge to simulate the wall charge has the disadvantage that such a source is associated with a field singularity, and thus it is not possible to represent the maximum field at the void wall in a realistic manner. To overcome this limitation, other representations of wall charges are presently under examination.

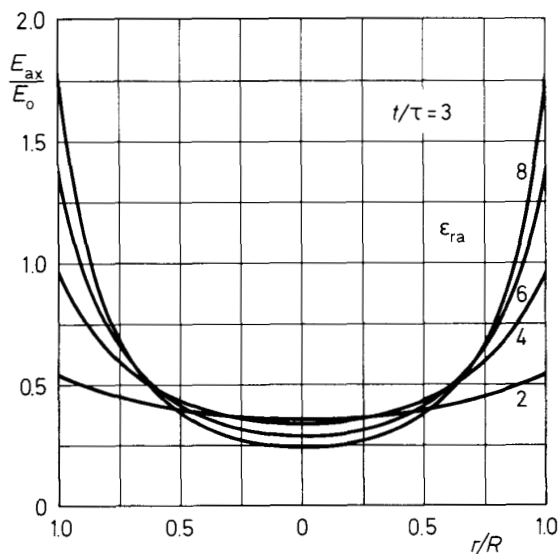


Figure 6.

Variation of the void axial electric field E_{ax} : influence of bulk permittivity.

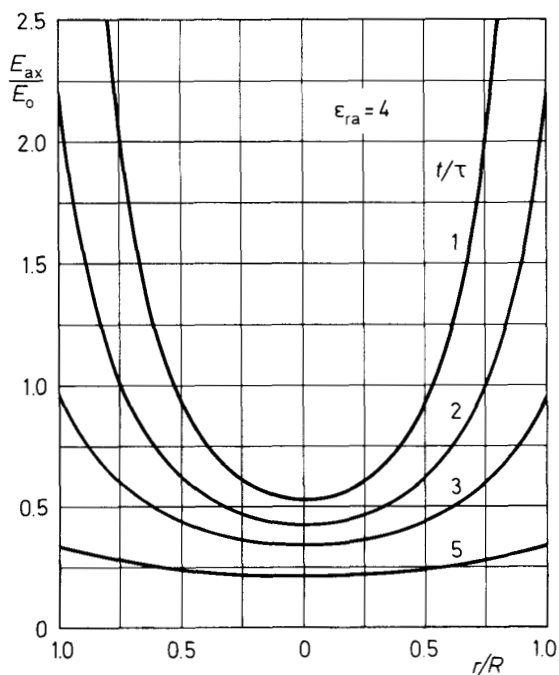


Figure 7.

Variation of the void axial electric field E_{ax} : influence of time.

REFERENCES

- [1] I. W. McAllister, "Surface Current Density \vec{K} : An Introduction", IEEE Trans. Elect. Insul., Vol. 26, pp. 416-417, 1991.
- [2] I. W. McAllister, "Electric Fields Associated with Transient Surface Currents", J. Appl. Phys., Vol. 71, pp. 3633-3635, 1992.
- [3] J. A. Stratton, *Electromagnetic Theory*, McGraw-Hill New York 1941.
- [4] E. Weber, *Electromagnetic Fields, Mapping of Fields*, Vol. I, J. Wiley New York 1950.

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